NSN 5962-01-206-1989

Memory Microcircuit - Page 1 of 1



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Body Length:

1.111 inches

Body Width:

Between 0.350 inches and 0.410 inches

Body Height:

Between 0.155 inches and 0.210 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Ea-6b acft

Features Provided:

Programmed and electrostatic sensitive and burn in and bipolar and schottky and w/enable and 3-state output and asynchronous and

synchronous and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Case Outline Source And Designator:

D-7 mil-m-38510

Current Rating Per Characteristic:

185.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Memory Device Type:

Prom

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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